

isc N-Channel MOSFET Transistor

2SK987

DESCRIPTION

- Drain Current –I_D=5A@ T_C=25 °C
- · Drain Source Voltage-
 - : V_{DSS}= 500V(Min)
- · Minimum Lot-to-Lot variations for robust device performance and reliable operation

D(2) PIN 1. Gate 2.Drain 1 2 3 3.Source TO-220Fa package

APPLICATIONS

· Designed for high voltage, high speed power switching

ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	ARAMETER	VALUE	UNIT
V _{DSS}	Drain-Source Voltage (V _{GS} =0)	500	V
V _{GS}	Gate-Source Voltage	±20	V
I _D	Drain Current-continuous@ TC=25℃	5	А
P _{tot}	Total Dissipation@TC=25℃	40	W
T _j	Max. Operating Junction Temperature	150	$^{\circ}$ C
T _{stg}	Storage Temperature Range	-55~150	$^{\circ}$

	m	m
MIC	MIN	MAX
Α	16.85	17.15
В	9.54	10.10
D F G	4.35	4.65
D	0.75	0.90
F	3.20	3.40
G	6.90	7.20
Н	3.80	4.20
J	0.45	0.75
K	13.35	13.80
L	1.10	1.30
N	4.98	5.18
Q	4.85	5.15
R	2.55	3.25
S	2.70	2.90
U	1.75	2.05
٧	1.30	1.50

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT	
R _{th j-c}	Thermal Resistance,Junction to Case	0.83	°C/W	
R _{th j-a}	Thermal Resistance,Junction to Ambient	35	°C/W	



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• ELECTRICAL CHARACTERISTICS (Tc=25°C)

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT
$V_{(BR)DSS}$	Drain-Source Breakdown Voltage	V _{GS} =0; I _D = 10mA	500			V
V _{GS(th)}	Gate Threshold Voltage	V _{DS} =0; I _D =1mA	2.0		4.0	V
R _{DS(on)}	Drain-Source On-stage Resistance	V _{GS} =10V; I _D =3A			1.6	Ω
I _{GSS}	Gate Source Leakage Current	V _{GS} = ±20V;V _{DS} = 0			±100	nA
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} =500V; V _{GS} = 0			500	uA



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